

	Type	L #	Hits	Search Text	DBs	Comments
1	BRS	L1	149601	438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
2	BRS	L2	6	1 and ((plasma near treat\$4) near (ARC or anti-reflect\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
3	BRS	L4	0	3 and (prevent\$3 near lift\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
4	BRS	L5	1	3 and adhesive\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
5	BRS	L6	0	3 and groove	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
6	BRS	L3	6	2 and photoresist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
7	BRS	L7	20	kwon-young-min.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
8	BRS	L8	0	7 and ((plasma near treat\$4) near (ARC or anti-reflect\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
9	BRS	L9	4272	photolithography.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
10	BRS	L10	3	9 and ((plasma or treat\$4) near (ARC or anti-reflect\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
11	BRS	L11	0	10 and groove	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
12	BRS	L12	65234	photolithography	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
13	BRS	L13	92	12 and ((plasma or treat\$4) near (ARC or anti-reflect\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
14	BRS	L14	50	13 and photoresist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
15	BRS	L15	4	14 and groove	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	